

Elimination of trap density by NH4Cl passivation for high‑performance perovskite solar cells

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Received: 30 June 2023 / Accepted: 2 October 2023 / Published online: 17 October 2023 © The Author(s), under exclusive licence to Springer-Verlag GmbH, DE part of Springer Nature 2023

Abstract

Different concentrations of NH₄Cl are introduced to MAPbI₃ precursor solution, planar MAPbI₃ perovskite films, and solar cells' performance with or without NH₄Cl have been studied. The NH₄Cl/MAPbI₃ films exhibit increased grain size and narrowed grain boundaries. The light absorption of perovskite films with different concentrations of NH₄Cl was also evaluated. To understand the growth of perovskite films with $NH₄Cl$ added to perovskite precursor solutions, XRD and XPS spectroscopy were conducted on different perovskite film samples. By adding $NH₄Cl$, the MAPbI₃ film shows good crystal quality and the shift of Pb peaks indicates that $NH₄Cl$ is not physically mixed but chemically incorporated into $MAPbI₃$ films. We attribute the effect to Cl ions of $NH₄Cl$ combining with free lead ions of $MAPbI₃$ so as to fill the vacancy of volatile I ions in the NH₄Cl–MAPbI₃ films. The 20 mg NH₄Cl–based device showed an enhanced performance of a PCE of 13.67% compared to the device without adding NH₄Cl with a PCE of 10.24%. The introduction of 20 mg NH₄Cl achieved the best passivation effect. Using a 20 mg NH₄Cl device, the trap density can be reduced to 0.84×10^{16} cm⁻³, resulting in more efficient charge removal from the surface and improved performance.

Keywords NH₄Cl · Passivation · Defect · Perovskite

1 Introduction

In the past few decades, organic and inorganic hybrid perovskite have attracted more and more attention due to their superior photoelectric properties $[1-4]$ $[1-4]$ $[1-4]$. The power conversion efficiency (PCE) of single-junction perovskite solar cells has recently increased from 3.8% to more than 25% [[5–](#page-5-2)[8](#page-5-3)]. Inverted perovskite solar cells offer high stability, low hysteresis, and lightweight characteristics, making them suitable for great application in wearable electronic devices and tandem perovskite solar cells [\[9](#page-5-4)[–11](#page-5-5)]. However, the PCE of inverted perovskite solar cells has been lower than that of

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regular perovskite solar cells resulting from the perovskite flm serious recombination loss [[12,](#page-5-6) [13\]](#page-5-7). A large number of traps on the grain boundary of perovskite flms hinder carrier separation and lead to charge non-radiative recombination, which is an important reason for the low performance of inverted perovskite solar cells [\[14](#page-5-8), [15\]](#page-5-9). Therefore, improving the quality of the perovskite flm is very important for the efficiency and stability of inverted perovskite solar cells. A simple and efective method to increase the grain sizes of perovskite flms is urgently needed. Furthermore, passivation strategies were confirmed as an efficient method of suppressing perovskite flm defects [\[16](#page-6-0)[–18\]](#page-6-1).

In the process of preparation of perovskite flms, improving the quality of perovskite flms by adding additives with specifc functional groups is widely discussed. The addition of specifc functional groups can efectively passivate the defects in the perovskite matrix, such as amine $(-NH₂)$, hydroxyl ($-OH$), acid ($-SO₃$), or halides, can effectively passivate the defects in the perovskite matrix, and improve the quality and optoelectronic properties of the flms [[19](#page-6-2)[–23](#page-6-3)]. When Cl[−] is added to iodized perovskites, it can replace iodine, reduce the number of iodine vacancies, achieve better crystallization quality, and improve the stability of the

material $[24]$ $[24]$. It has been found that the addition of ammonium cation (NH4 +) into organic perovskites can regulate and optimize the microstructure of the perovskite film, which in turn enhances its performance. In addition, NH_4^+ cations could properly fll into the vacancies of MA, or enter into the interstitial places of MA to passivate defects. The NH_4^+ cation compared to the Na⁺ or K⁺ due to its larger ion radius, and the cation with a larger ionic radius makes it more difficult to enter the MA ionic gap, thus reducing the defects caused by the addition of too much non-perovskite phase to the perovskite flm, which can better passivate the trap states in perovskite [[25](#page-6-5), [26](#page-6-6)].

In this manuscript, ammonium chloride $(NH₄Cl)$ is introduced into a perovskite precursor solution to optimize the properties of perovskite flms. For comparison, NH4Cl-free inverse structures were also prepared under the same fabrication conditions. With the addition of $NH₄Cl$, the crystallites of perovskite flms were enhanced and grain boundaries were reduced. X-ray photoelectron spectroscopy (XPS) was used to detect the effect of $NH₄Cl$ on perovskite films. These results show that 20 mg $NH₄Cl$ effectively passivates perovskite flms, and the density of trap states was reduced. Compared with the pure perovskite device with a PCE of 10.24%, the efficiency of the perovskite solar cell based on 20 mg NH4Cl reaches 13.67%. Our results provide a surface treatment method for the inverted perovskite solar cells that can deliver high-efficiency outcomes. This strategy offers the obvious potential for perovskite-based photovoltaic technologies and greatly promotes their development. For another, larger perovskite grains have a superior photoelectric response, making them ideal for use in photoconductive detectors and photosensitive sensors. In addition, the process of passivating perovskites has several benefts, including efficient electron–hole pair separation, faster charge migration, and higher stability. These advantages are of great signifcance in the feld of photocatalysis and photovoltaic power generation and are a great progress in the development of clean energy [\[27\]](#page-6-7).

2 Experimental section

2.1 Experiment materials

Lead iodide (PbI₂, Aladdin, 99.9%), methylammonium iodide (CH₃NH₃I, Macklin, 99.5%), dimethyl sulfoxide (DMSO, Aladdin, 99.9%), γ-butyrolactone (GBL, J&K Scientifc Ltd, 99%), 3,4-oxyethyleneoxythiophene-poly (styrene sulfonate) (PEDOT:PSS, J&K Scientifc Ltd.), [6,6]-phenyl-C61-butyric acid methyl ester (PCBM, Bide medicine, 99.7%), chlorobenzene $(C_6H_5Cl, J&K$ Scientific Ltd. 98.0%), anhydrous ethanol(C_2H_6O , Lingfeng, 99.7%),

bathocuproine (BCP, Baolaite, 99%), and ammonium chloride(NH₄Cl, 99.5%).

2.2 Device fabrication

ITO glass is cleaned with ethanol and acetone for 30 min to remove the pollutants from the glass surface and irradiated with ultraviolet to change its hydrophobicity. The ITO glass was then placed in a spin coater. 80 μL PEDOT:PSS is spin-coated on the ITO at 4000 rpm for 30 s, then annealed at 110 °C for 30 min. Next, 50 μ L CH₃NH₃PbI₃ precursor solution (470.9 mg PbI₂, 162.4 mg MAI in a mixture of 0.7 mL GBL and 0.3 mL DMSO) was spincoated on the PEDOT:PSS layer at 1500 rpm for 20 s and 4000 rpm for 40 s, then annealed at 110 \degree C for 10 min. 50 μL PCBM spin-coated on the $CH_3NH_3PbI_3$ layer at 2000 rpm for 30 s, then annealed at 90 °C for 10 min. 50 μL BCP spin-coated on the PCBM layer at 2000 rpm for 20 s, then annealed at 80 °C for 10 min. PCBM is considered an electron transport layer (ETL), and BCP promotes the charge transfer between the ETL and Ag electrode. Finally, the 100 nm Ag stick electrode was evaporated on the BCP layer by using vacuum evaporation coating technology (vacuum is 8.0×10^{-4} pa, film deposition rate is $0.2 \text{ Å/s}.$

 $CH_3NH_3PbI_3$ with NH₄Cl: 10 mg, 20 mg, and 30 mg $NH₄Cl$ were added to 1 ml of the perovskite precursor solution.

2.3 Characterization methods

The surface morphology and the crystallinity of perovskite flms were characterized by scanning electron microscopy (SEM, Gemini-300, Carl Zeiss, Germany). The crystallinity of perovskite was measured by X-ray difraction technique (XRD, Rigaku Ultima IV, Japan). The absorption spectra of perovskite flms were conducted on a UV/vis spectrophotometer (UV-1800, Shimadzu). Raman spectroscopy used for detection is Advantage NIR spectrometer, Deltanu. Elemental analysis of perovskite flms with ammonium chloride was carried out by X-ray photoelectron spectrometer (XPS, K-Alpha+, America). The excitation source was the monochromatic Al Kα X-ray beam operated at 72 W, and the electron emission angle was 0° . The energy step was 0.05 eV for detail spectra and 1 eV for survey spectra. The size of the analyzed sample area was 400 μm. The sample wasn't cleaned with Ar^+ ion sputtering before XPS measurement and we don't use charge neutralizer in our operation. The performance of PSCs was assessed by a photovoltaic system (AM 1.5 G, 100 mW/cm2, Growntech. INC, IV Test Station 2000 AAA).

3 Results and discussion

The cuboid growth of $MAPbI₃$ here can be optimized by adjusting the $NH₄Cl$ concentration in perovskite precursors, as can be observed by scanning electron microscopy (SEM). As shown in Fig. [1](#page-2-0)(a), the size of the neat $MAPbI₃$ perovskite flm crystal is smaller and the surface is relatively smooth. With 10 mg $NH₄Cl$ added to the MAPbI₃ precursor solution, the morphology of the perovskite flm changes in Fig. [1\(](#page-2-0)b), and the grain size tends to increase. After 20 mg NH4Cl is added, the crystal size further increases and the gap between the grain boundaries narrows (Fig. $1(c)$ $1(c)$). Increased crystal size and narrowed grain boundaries are conducive to reducing defects of the perovskite flms, which will be discussed later. Figure $1(d)$ $1(d)$ shows that the crystal size increases a lot by adding 30 mg NH₄Cl to the MAPbI₃ precursor solution, but the aggregation of grains also leads to large gaps, which causes direct contact between ETL and the hole transport layer (HTL). In the experiment, the MAPbI₃ precursor solution close to saturation, and even some turbid precipitation appearing, indicate that the passivation efect of NH4Cl has reached the limit.

The light absorption of perovskite flms with diferent concentrations of $NH₄Cl$ was also evaluated by a UV–Vis spectrophotometer. Neat perovskite has a wide range of light absorption, and it also shows a strong absorption around 750 nm [[28\]](#page-6-8). From Fig. [1](#page-2-0)(e), perovskite exhibits diferent light absorption after the addition of $NH₄Cl$ in the wavelength range of 600 nm to 800 nm. The absorption of perovskite films is enhanced after the addition of $NH₄Cl$, which is due to the larger grain sizes of the $MAPbI₃$ film. The greater the crystal size and narrower the grain boundaries with 20 mg $NH₄Cl$, the more effectively it can absorb light. Because of the infuence of the high-angle boundary with $30 \text{ mg NH}_4\text{Cl}$, the surface morphology of the film is damaged, and the absorption of perovskite flm also weakens.

To understand the growth of perovskite films with $NH₄Cl$ added to perovskite precursor solutions, XRD (X-ray diffraction) is conducted on diferent perovskite flm samples. As shown in Fig. [1](#page-2-0)f, the diffraction peak angles of $MAPbI₃$ are located at 14.1°, 28.4°, and 31.8°, corresponding to the (110), (220), and (310) planes of perovskite crystal structure [[29,](#page-6-9) [30](#page-6-10)]. The weak PbI_2 peaks (12.8°) indicate that PbI_2 is almost completely transformed into $MAPbI₃$. By comparing the difraction peak intensity of perovskite crystals, it is found that the crystal quality of $MAPbI₃$ film improves well after adding $NH₄Cl$, and the effect was the best for adding 20 mg NH₄Cl. The addition of 30 mg NH₄Cl to MAPbI₃ flms causes a weakening of their difraction peak, suggesting that an increase in NH₄Cl occurrence negatively affects the flm. These results are consistent with SEM morphology and absorption data.

Fig. 1 SEM images of the perovskite flms without (**a**) or with diferent concentrations (10 mg (**b**), 20 mg (**c**), 30 mg (**d**)) of NH4Cl to perovskite precursor solution, (**e**) Absorption and (**f**) XRD spectroscopy of the perovskite flms with or without NH4Cl

Furthermore, we study the reasons why adding $NH₄Cl$ improved the characteristics of $MAPbI₃$ films. From Fig. [2](#page-3-0)a, the Pb 4f XPS spectra show that the Pb 4f peaks for perovskite films with 20 mg $NH₄Cl$ shift toward a higher binding energy compared to neat MAPbI₃ film. The shift of Pb peaks indicates that $NH₄Cl$ is not only physically mixed but chemically incorporated into $MAPbI₃$ films, and we suppose the I-Pb-Cl structure is likely formed in the $NH_4Cl-MAPbI_3$ flms. To validate our hypothesis, we examine the XPS spectra of other elements. As shown in Fig. 2b, c, I 3d and N 1s characteristic peaks show some displacement of binding energy, which is attributed to the combination of Pb–Cl. Cl 3d characteristic peaks are also shown in Fig. [2](#page-3-0)d, which indicates that $NH₄Cl$ has been successfully combined with $MAPbI₃$ films. It can be seen that 20 mg NH₄Cl combined with $MAPbI₃$ film has the maximal relative content of Cl, which means that more Cl ions remain in the perovskite and bind with free Pb ions. Cl ions are combined with free Pb ions to fll the vacancy of volatile I ions, indicating that $NH₄Cl$ has a passivation effect on $MAPbI₃$ films. The added NH₄Cl effectively passivates the grain boundary defects of perovskite to promote the nucleation and crystal growth of the $MAPbI₃$ film, and fully covers the substrate to obtain high-quality perovskite flms, which helps improve the performance of perovskite solar cells.

To estimate the photovoltaic performance enhanced with NH4Cl added by increasing the light absorption and larger crystal size and narrowed grain boundaries. We fabricated inverted perovskite solar cells with the structure of ITO/ $PEDOT: PSS/MAPbI₃$ (with or without $NH₄Cl$)/ $PCBM/BCP/$ Ag.

The current density and voltage of diferent devices are shown in Fig. [3](#page-4-0)a, and their corresponding parameters are listed in Table [1.](#page-4-1) The device without adding $NH₄Cl$ exhibits a PCE of 10.24%, with an open-circuit voltage (V_{oc}) of 0.87 V, a short-circuit current density $(J_{\rm sc})$ of 17.06 mA/cm² and 68.89% fll factor (FF). The small values of these parameters are mainly the result of the recombination caused by defects in perovskite solar cells. The more grain boundaries, the more energy loss, the faster the decay of charge carriers, and the lower the charge transfer efficiency. After adding $NH₄Cl$ to the perovskite precursor solution, the device performance improves, so these results indicate that the $NH₄Cl$ is an efective passivation for the perovskite defects.

After adding 10 mg $NH₄Cl$, the PCE of the device increases to 12.31%, and, FF also greatly improves, indicating that the device defects are reduced by $NH₄Cl$. Device PCE reaches the best value of 13.67% when adding 20 mg $NH₄Cl$, indicating that the introduction of 20 mg NH₄Cl achieves the best passivation effect. The improved V_{oc} and FF values result from the effective passivation of $NH₄Cl$, and the enhancement is attributed to the good crystallization of $NH_4Cl-MAPbI_3$ films. The neat perovskite device and best device hysteresis have also been studied, as shown in Fig. [3](#page-4-0)b, c. These two devices present no obvious hysteresis. The device parameters of 30 mg $NH₄Cl$ once again prove

Fig. 2 (a) XPS spectra of Pb 4f, (**b**) I 3d and (**c**) N 1s characteristic peaks without or with 20 mg NH4Cl. (**d**) Cl 3d characteristic peaks without or with different NH₄Cl concentrations

Fig. 3 (**a**) The current density and voltage curves of diferent NH4Cl-based devices. Forward and reverse scan directions without (**b**) or with (**c**) 20 mg NH4Cl-based devices. The neat perovskite

Table 1 *J*–*V* characteristics parameters of devices with diferent $NH₄Cl$ concentrations and without the $NH₄Cl$ on the perovskite layers

Devices	$V_{oc}(V)$	J_{sc} (mA/cm ²)	FF(%)	$PCE (\%)$
θ	0.87	17.06	68.89	10.24
10	0.90	19.61	69.64	12.31
20	0.92	20.87	71.30	13.67
30	0.90	19.81	64.98	11.60

that excessive NH4Cl addition will destroy the photoelectric properties of MAPbI₃ films.

To investigate the defect passivation efect in detail, we measured the neat perovskite device and the best device dark current density and trap density of state. In this work, both devices have good diode properties and can provide good photocurrent (Fig. [3](#page-4-0)d). The utilization of a 20 mg $NH₄Cl-based device results in a dark current reduction,$ which means less current leakage, helps to reduce the shunt resistance of the device and facilitates charge transfers (CT) between interface layers, thus enabling the device to show higher conversion efficiency.

To calculate the trap state of the device with or without $20 \text{ mg NH}_4\text{Cl}$, hole-only devices are equipped with a structure of ITO/PEDOT:PSS/Perovskite/MoO₃/Au. According

device and 20 mg NH4Cl-based devices' dark current density (**d**) and trap state density (**e**). (**f**) Raman spectroscopy of CuPc on perovskite films with or without $NH₄Cl$

to the space charge limited current (SCLC) model, the start of the trap filling limit voltage (V_{TFL}) of the device with 20 mg NH₄Cl added shows a relatively low value of 0.68 V (Fig. [3](#page-4-0)e), whereas 0.74 V V_{TEL} is obtained for the device without passivation treatment. Using the following formula between V_{TFL} and defect state density (N_t):

$$
N_t = \frac{2\epsilon_0 \epsilon V_{TFL}}{eL^2}.
$$

e is the basic charge, L is the thickness of perovskite layers, ε is the relative dielectric constant of perovskite films, ε_0 is the permittivity of vacuum. According to the values of V_{TH} , the N_t of the neat perovskite device is calculated with a value of 0.91×10^{16} cm⁻³, and the N_t of 20 mg NH₄Cl-based device decreases to 0.84× 10¹⁶ cm−3. Reduced trap density leads to efficient charge extraction from the surface, which limits $V_{\alpha c}$ losses and improves FF, and this is consistent with current density and voltage results. This also proves that $NH₄Cl$ can efectively passivate perovskite flm defects.

To further study the interaction between $NH₄Cl$ and perovskite flms, Raman spectroscopy is used to study the properties of perovskite flms. From Fig. [3f](#page-4-0), a CuPc solution with a concentration of 1×10^{-3} M is deposited on perovskite films with or without $NH₄Cl$, and then quickly

dried in a nitrogen glove box. The Raman spectral integration time is set to 5 s with a resolution of 2 cm^{-1} . The characteristic peaks of CuPc appear at 635 cm^{-1} , 732 cm⁻¹, 1130 cm⁻¹, 1328 cm⁻¹, and 1517 cm⁻¹, respectively. Among them, the flm with the strongest characteristic peak for 20 mg $NH₄Cl$, indicates that the degree of passivation of $MAPbI₃$ film is the highest at this time, and the flling of inherent defects enhances charge transfers, which is consistent with our previous research results.

4 Conclusion

We have shown an efficient way to passivate perovskite films by inserting different concentrations of $NH₄Cl$ into the MAPbI₃ precursor solution. The defects of $NH₄Cl$ passivated perovskite flms result in larger grains and fewer grain boundaries, thus enhancing the electron–hole transport rate. The larger crystal size and narrowed grain boundaries with $NH₄Cl$ lead to a better increase in their absorption. The $MAPbI₃$ film exhibits optimal crystal structure when 20 mg of $NH₄Cl$ is added to the SEM morphology and absorption data. The reason why adding $NH₄Cl$ improved the characteristics of $MAPbI₃$ films is that Cl ions combine with free lead ions so as to fll the vacancy of volatile I ions. The best device PCE obtained a value of 13.67% when adding 20 mg NH₄Cl, indicating that the introduction of 20 mg $NH₄Cl$ achieved the best passivation efect and showed lower trap density with a value of 0.84×10^{16} cm⁻³.

Acknowledgements We acknowledge the financial support from the National Natural Science Foundation of China (NSFC) (*Nos.* 61701261), the Natural Science Foundation of Jiangsu Province (*Nos.* BK20160417) and the Innovation and Entrepreneurship Training program for College students in Jiangsu Province of China (*Nos.* 202310304004Z).

Author contributions QY: Investigation, Methodology, Writing original draft. FZ: Investigation, Writing. YT: Conceptualization. CP: Visualization. CW: Review. YJ: Review. MX: Writing—review and editing. TX: Review and Supervision.

Data availability Data will be made available on request.

Declarations

Conflict of interest The authors declare that they have no known competing fnancial interests or personal relationships that could have appeared to infuence the work reported in this paper.

Ethical approval The authors declare that this manuscript is original, has not been published before, and is not currently being considered for publication elsewhere. This submission in its present form is approved by all authors.

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